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| SERIAL NUMBER 10/036,156 | FILING OR 371(c) DATE 12/26/2001 RULE | CLASS 438 | GROUP ART UNIT 2813 | ATTORNEY DOCKET NO. 29936/37830 | |
| APPLICANTS Dae Gyu Park, Kyungki-Do, KOREA, REPUBLIC OF; Heung Jae Cho, Kyungki-Do, KOREA, REPUBLIC OF; Kwan Yong lim, Kyungki-Do, KOREA, REPUBLIC OF; | | | | | |
| ** CONTINUING DATA ***** ** FOREIGN APPLICATIONS ***** REPUBLIC OF KOREA 2000-85582 12/29/2000 | | | | | |
| IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 01/30/2002 | | | | | |
| Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after met Verified and Acknowledged <u>Allowance</u> Examiner's Signature _____ Initials _____ | | STATE OR COUNTRY KOREA, REPUBLIC OF | SHEETS DRAWING 4 | TOTAL CLAIMS 12 | INDEPENDENT CLAIMS 1 |
| ADDRESS 04743 | | | | | |
| TITLE METHOD OF FORMING A METAL GATE IN A SEMICONDUCTOR DEVICE USING ATOMIC LAYER DEPOSITION PROCESS | | | | | |
| FILING FEE RECEIVED 740 | FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following: | | <input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit | | |